

(19) United States

(12) Patent Application Publication (10) Pub. No.: US 2022/0393686 A1 Manipatruni et al.

(43) Pub. Date:

Dec. 8, 2022

(54) FABRICATION OF A MAJORITY LOGIC GATE HAVING NON-LINEAR INPUT **CAPACITORS**

(71) Applicant: Kepler Computing Inc., San Francisco, CA (US)

(72) Inventors: Sasikanth Manipatruni, Portland, OR (US); Rafael Rios, Austin, TX (US); Neal Reynolds, Bremerton, WA (US); Ikenna Odinaka, Durham, NC (US); Robert Menezes, Portland, OR (US); Rajeev Kumar Dokania, Beaverton, OR (US); Ramamoorthy Ramesh, Moraga, CA (US); Amrita Mathuriya, Portland, OR (US)

(73) Assignee: Kepler Computing Inc., San Francisco, CA (US)

Appl. No.: 17/808,290

(22) Filed: Jun. 22, 2022

Related U.S. Application Data

Continuation of application No. 17/327,649, filed on May 21, 2021, now Pat. No. 11,394,387, which is a continuation of application No. 17/327,614, filed on May 21, 2021, now Pat. No. 11,277,137.

Publication Classification

(51) Int. Cl. H03K 19/185 (2006.01)H03K 19/23 (2006.01)H01L 49/02 (2006.01)

(52)U.S. Cl. CPC (2013.01); H01L 28/65 (2013.01); H01L 28/55 (2013.01); H03K 19/21 (2013.01)

(57)**ABSTRACT**

A new class of logic gates are presented that use non-linear polar material. The logic gates include multi-input majority gates. Input signals in the form of digital signals are driven to non-linear input capacitors on their respective first terminals. The second terminals of the non-linear input capacitors are coupled a summing node which provides a majority function of the inputs. The majority node is then coupled driver circuitry which can be any suitable logic gate such as a buffer, inverter, NAND gate, NOR gate, etc. In the multi-input majority or minority gates, the non-linear charge response from the non-linear input capacitors results in output voltages close to or at rail-to-rail voltage levels. Bringing the majority output close to rail-to-rail voltage eliminates the high leakage problem faced from majority gates formed using linear input capacitors.



